# HAMAMATSU

BUSINESS

#### Features

- •Emission wavelength:4.57 μm (Typ.)
- •Output power:20 mW (Min.)

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•Threshold current:1.0 A (Max.)

ApplicationsTrace gas analysis (N2O, CO)



#### Outline

Quantum Cascade Lasers, using structures of SPC (Single Phonon-Continuum) depopulation and DFB (Distributed Feedback), emit CW (Continuous Wave) mid-IR laser under room temperature.

By controlling the chip's operating temperature through the Peltier element installed in the HHL package, it is possible to tune the emission wavelength without mode hopping while keeping longitudinal single mode operation.

#### Absolute and characteristics

| T <sub>op(qcl)</sub> = +20 °C, unless otherwise spec |                      |   |        |  |
|--|----------------------|---|--------|--|
| Characteristics                                      | Symbols              | Ratings   | Units  |  |
| Forward current <sup>*1)</sup>                       | l <sub>f</sub>       | This product has individual difference.                 | А      |  |
| Forward voltage <sup>*1)</sup>                       | V <sub>f</sub>       | Confirm data sheet attached to a product <sup>*2)</sup> | V      |  |
| Reverse voltage <sup>*1)</sup>                       | Vr                   | 0.0   | V      |  |
| Change speed of forward current *3)                  | -                    | 5   | mA/s   |  |
| TEC current (cooling mode) *4)                       | l.                   | +3.7  | А      |  |
| TEC current (heating mode) *4)                       | "C                   | -1.5  | А      |  |
| TEC voltage  | Vc                   | ±13.0   | V      |  |
| Operating temperature (case) *5) *6)                 | T <sub>op(c)</sub>   | +10 to +60  | °C     |  |
| Operating temperature (QCL) *7)                      | T <sub>op(qcl)</sub> | 0 to +55  | °C     |  |
| Change speed of operating temperature *8)            | -                    | 10  | °C/min |  |
| Storage temperature *5)                              | T <sub>stg</sub>     | -20 to +65  | °C     |  |

\*1) Confirm data sheet attached to a product. Sensitive to electrical surges and instability. Reverse current/voltage cause damage in laser specifications and out of warranty. \*2) Necessary specifications of power supply : Ir ≥ 1.3 A, Vr ≥ 16 V.

\*3) Speed when changing the forward currrent (If).

\*4) Even if TEC current (I<sub>c</sub>) is below the absolute maximum, insufficient heat dissipation from this product may cause damage in laser and TEC specifications and out of warranty. Especially there are possibilities of damage, degradation and less reliability when TEC is operated in heating mode since heated-up side (laser chip) is thermally isolated from case of package and ambience. Refer to schematic configuration in 3-2-4.

\*5) Avoid water condensation.

\*6) Temperatures of case (body) of HHL-package.

\*7) Temperatures of QC-laser when operated; should be monitored by the built-in thermistor for  $T_{op(qci)}$ .

\*8) Speed when changing the operation temperature  $(T_{op(qcl)})$  controlled by the built-in TEC.

# Specifications (laser)

| Characteristics                 | Symbols              | Test conditions                         | Min.  | Тур. | Max.   | Units |
|---------------------------------|----------------------|---|-------|------|--------|-------|
| Operating temperature (QCL) (2) | T <sub>op(qcl)</sub> | K <sup>(1)</sup> =2190 cm <sup>-1</sup> | +10   | -    | +50    | °C    |
| Spectral linewidth (3)          | $\Delta K_{L}$       | K <sup>(1)</sup> =2190 cm <sup>-1</sup> | -     | -    | 0.2(4) | cm⁻¹  |
| Wavenumber tuning range (5)     | ΔΚτ                  | K <sup>(1)</sup> =2190 cm <sup>-1</sup> | ±1.0  | -    | -      | cm⁻¹  |
| Radiant power                   | φe                   | K <sup>(1)</sup> =2190 cm <sup>-1</sup> | 20    | -    | -      | mW    |
| Threshold current               | l <sub>th</sub>      | T <sub>op(qcl)</sub> =+20 °C            | -     | -    | 1.0    | Α     |
| Side mode suppression ratio     | SMSR                 | T <sub>op(qcl)</sub> =+20 °C            | 25(4) | -    | -      | dB    |

(1) K: Emission wavenumber (cm<sup>-1</sup>).

(2) This product is able to emit the target wavenumber at a certain  $T_{op(qc)}$  within the specified temperature range.

(3) FWHM.

(4) These values are limited by resolution and singnal-to-noise ratio of instrument when tested.

(5) Continuously wavenumber scan range; Center of the tunability range is the emission wavenumber (K).

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#### Typical characteristics



Forward current If (A)

| Characteristics                       | Symbols         | Conditions                    | Typical values              |
|---------------------------------------|-----------------|-------------------------------|-----------------------------|
| Temperature coefficient of wavenumber | δK <sub>T</sub> | I <sub>f</sub> = const.       | –0.18 cm <sup>-1</sup> /°C  |
| Current coefficient of wavenumber     | δK <sub>c</sub> | T <sub>op(qcl)</sub> = const. | -0.015 cm <sup>-1</sup> /mA |

#### TEC

| Characteristics                | Symbols           | Test conditions  | Specifications |
|--------------------------------|-------------------|--|----------------|
| Maximum temperature difference | $\Delta T_{max}$  | T <sub>h</sub> =27 °C, in N <sub>2</sub> , Q <sub>c</sub> =0, I <sub>c</sub> =+3.7 A | >40 °C         |
| Maximum heat pumping capacity  | Q <sub>cmax</sub> | $T_h$ = 27 °C, in N <sub>2</sub> , I <sub>c</sub> =+3.7 A, $\Delta$ T=0              | >18 W          |
| AC resistance                  | ACR               | T <sub>h</sub> =27 °C, I <sub>c</sub> =0.1 mA, 1 kHz                                 | 2.0 Ω±0.4 Ω    |

Note)  $\Delta T$ : Temperature difference

Qc: Heat pumping capacity

Th: Temperature of TEC's hot side surface (TEC: cooling mode)

#### Thermistor

| Characteristics | Symbols         | Test conditions | Specifications |
|-----------------|-----------------|-----------------|----------------|
| Resistance      | R <sub>25</sub> | 25 °C           | 10 kΩ±2.5 %    |
| Beta value      | В               | 0 °C / 100 °C   | 3450 K         |

Note) Same specifications for both thermisters of  $T_{op(qcl)}$  and  $T_{op(c)}$ .

# Thermistor configurations (schematic)



#### Window of HHL package

| Characteristics |                               | Specifications                                 |  |
|-----------------|-------------------------------|--|--|
| Material        |                               | ZnSe, Plano-Plano                              |  |
| Dimonsion       | Clear aperture <sup>(1)</sup> | φ4,4 mm  |  |
| Dimension       | Thickness                     | 0.7 mm   |  |
|                 | Coating                       | BBAR, both surface                             |  |
| Coating         | Bandwidth                     | 2500 cm <sup>-1</sup> to 1250 cm <sup>-1</sup> |  |
|                 | Transmittance <sup>(2)</sup>  | > 96 %   |  |

(1): Mechanical aperture of HHL package.

(2): Average in the bandwidth.

### Typical transmittance curve of the window



#### Necessary specifications of power supply for the laser (QCL)

| Characteristics | Specifications           |  |  |
|-----------------|--------------------------|--|--|
| Output current  | ≥1.3 A                   |  |  |
| Output voltage  | ≥16 V                    |  |  |
| Function        | Surge protect            |  |  |
| Function        | Constant current control |  |  |

#### Dimensional outline and pin connection (unit:mm)





\*1) Tolerance is +/- 0.3 mm unless specified. \*2) Edge of QCL chip and outside of the package.

σ

Laser chip

| Pin No. *3) | Function                            | Pin No. *3) | Function                          |
|-------------|-------------------------------------|-------------|-----------------------------------|
| 1           | TEC cathode (-)                     | 1           | QCL cathode (-)                   |
| 3           | N.C.                                | 8           | Thermistor, (T <sub>op(c)</sub> ) |
| (4)         | QCL anode (+)                       | 9           | Thermistor, (T <sub>op(c)</sub> ) |
| 5           | Thermistor, (T <sub>op(qcl)</sub> ) | 10          | TEC anode (+)                     |
| 6           | Thermistor, (T <sub>op(qcl)</sub> ) | -           | -                                 |

\*3) Pin of ③ is electrically connected to the case; package body. Other all pins are floating to the case.

**CLASS 3B LASER** Invisible Laser Radiation: Avoid Exposure to Beam

The Laser emits invisible laser radiation. The instrument which used the LASER, operated under ordinary conditions, is classified as Class 3B according to the laser product classification code IEC 60825-1. See IEC 60825-1 for more details and safety operation concerning the above countermeasures



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MAR. 2019